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# HMC373LP3

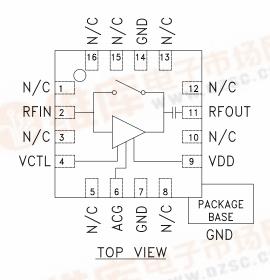
# GaAs PHEMT MMIC LOW NOISE AMPLIFIER w/ BYPASS MODE, 700 - 1000 MHz

# **Typical Applications**

The HMC373LP3 is ideal for basestation receivers:

- · GSM, GPRS & EDGE
- CDMA & W-CDMA
- Private Land Mobile Radio

# **Functional Diagram**



### **Features**

Noise Figure: 0.9 dB +35 dBm Output IP3

Gain: 14 dB

Low Loss LNA Bypass Path Single Supply: +5.0 V @ 90 mA 50 Ohm Matched Output

## General Description

The HMC373LP3 is a versatile, high dynamic range GaAs MMIC Low Noise Amplifier that integrates a low loss LNA bypass mode on the IC. The amplifier is ideal for GSM & CDMA cellular basestation frontend receivers operating between 700 and 1000 MHz and provides 0.9 dB noise figure, 14 dB of gain and +35 dBm IP3 from a single supply of +5.0V @ 90 mA. Input and output return losses are 28 and 12 dB respectively with the LNA requiring minimal external components to optimize the RF input match, RF ground and DC bias. By presenting an open or short circuit to a single control line, the LNA can be switched into a low 2.0 dB loss bypass mode reducing the current consumption to 10 µA. A low cost, leadless 3x3 mm QFN surface mount package (LP3) houses the low noise amplifier.

# Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = +5V

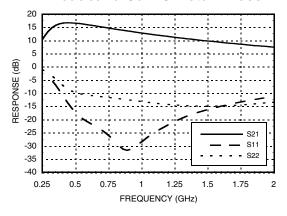
	LNA Mode			LNA Mode			Bypass Mode			14.7
Parameter		Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	810 - 960		700 - 1000		700 - 1000			MHz		
Gain	11.5	13.5	AK	10.5	14		-2.8	-2.0		dB
Gain Variation Over Temperature		0.008	0.015	9 -	0.008	0.015		0.002	0.004	dB / °C
Noise Figure	- 6	0.9	1.3		1.0	1.4				dB
Input Return Loss		28			25			30		dB
Output Return Loss		12			11			25		dB
Reverse Isolation		20			19					dB
Power for 1dB Compression (P1dB)*	18	21		17	20			30		dBm
Saturated Output Power (Psat)		22.5			22					dBm
Third Order Intercept (IP3)* (-20 dBm Input Power per tone, 1 MHz tone spacing)		35.5			35			50		dBm
Supply Current (Idd)		90			90			0.01		mA

P1dB and IP3 for LNA Mode are referenced to RFOUT while P1dB and IP3 for Bypass Mode are referenced to RFIN.

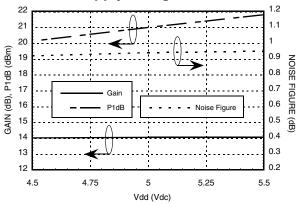


### LNA Broadband Gain & Return Loss

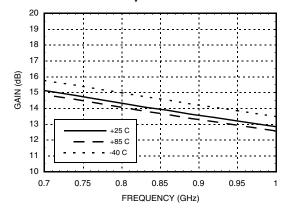
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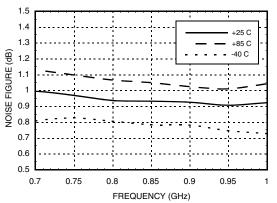
LNA – Gain, Noise Figure & Power vs. Supply Voltage @ 850 MHz



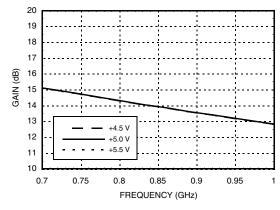
LNA Gain vs. Temperature



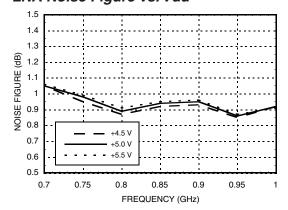
LNA Noise Figure vs. Temperature



LNA Gain vs. Vdd

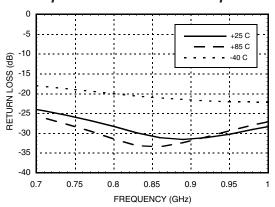


LNA Noise Figure vs. Vdd

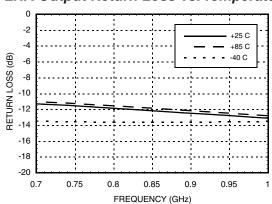




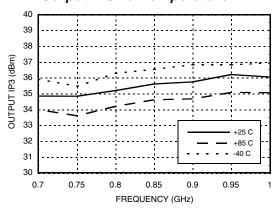
### LNA Input Return Loss vs. Temperature



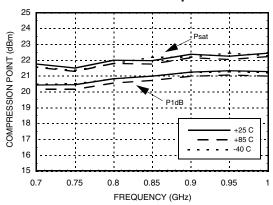
### LNA Output Return Loss vs. Temperature



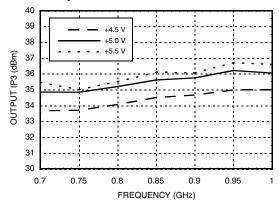
### LNA Output IP3 vs. Temperature



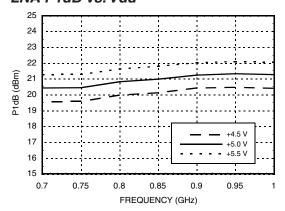
# LNA P1dB & Psat vs. Temperature



### LNA Output IP3 vs. Vdd



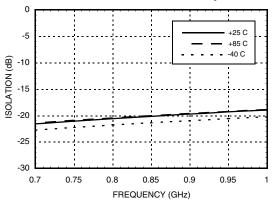
### LNA P1dB vs. Vdd



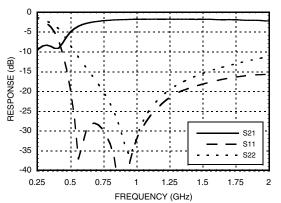


## LNA Reverse Isolation vs. Temperature

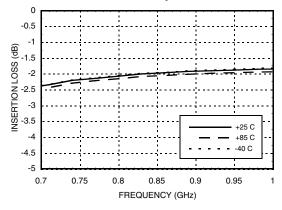
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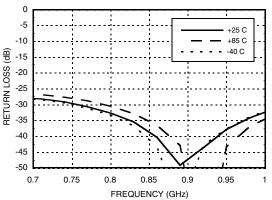
Bypass Mode Broadband Insertion Loss & Return Loss



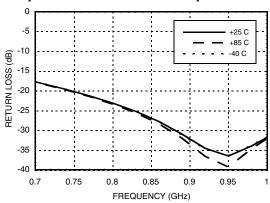
Bypass Mode Insertion Loss vs. Temperature



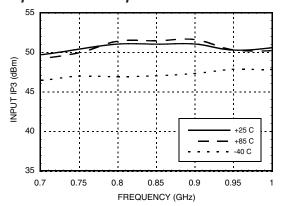
Bypass Mode Input Return Loss vs. Temperature



Bypass Mode Output Return Loss vs. Temperature



Bypass Mode Input IP3 vs. Temperature





# Absolute Maximum Ratings

+8.0 Vdc		
+15 dBm +30 dBm		
150 °C		
0.878 W		
74.1 °C/W		
-65 to +150° C		
-40 to +85° C		

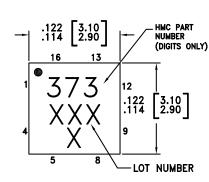
# Typical Supply Current vs. Vdd

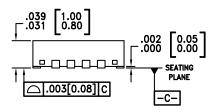
Vdd (Vdc)	Idd (mA)
+4.5	87
+5.0	90
+5.5	93

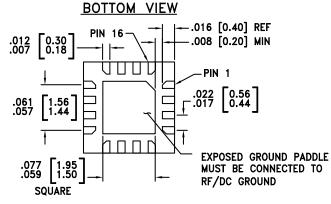
### Truth Table

LNA Mode	Vctl= Short Circuit to DC Ground
Bypass Mode	Vctl= Open Circuit

# **Outline Drawing**







- 1. MATERIAL PACKAGE BODY: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY
- 3. LEAD AND GROUND PADDLE PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 6. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 7. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

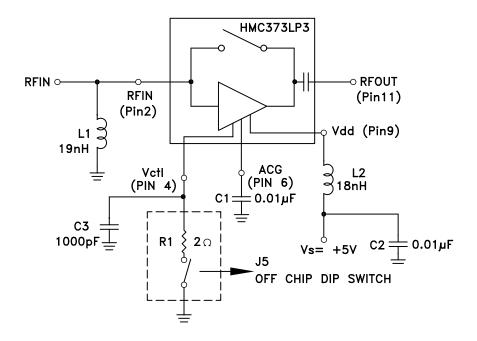


# Pin Descriptions

Pin Number	Function	Description	Interface Schematic	
1, 3, 5, 8, 10, 12, 13, 15, 16	N/C	No connection necessary.  These pins may be connected to RF/DC ground.		
2	RF IN	This pin is matched to 50 Ohms with a 19 nH inductor to ground. See Application Circuit.	RFIN O-	
4	Vctl	DC ground return. LNA is in high gain mode when a short circuit is introduced to this pin through an external switch. LNA is in bypass mode when open circuit is introduced	ACG VetI	
6	ACG	An external capacitor of 0.01µF to ground is required for low frequency bypassing. See Application Circuit for further details.	ACG Vctl	
7, 14	GND	These pins must be connected to RF/DC ground.	<u> </u>	
9	Vdd	Power supply voltage. Choke inductor and bypass capacitor are required. See application circuit.	ACG Vctl	
11	RF OUT	This pin is AC coupled and matched to 50 Ohms.		



### **Evaluation Board Circuit**



Note 1: Choose value of capacitor C1 for low frequency bypassing. A 0.01  $\mu$ F  $\pm$ 10% capacitor is recommended.

Note 2: Pin 4 (Vctl) is the DC ground return for the circuit. The LNA is in the high gain mode when a short circuit is introduced to this pin through an external switch. The LNA is in bypass mode when an open circuit is introduced. For the data presented, switching is done through a two position DIP switch (J5) in series with a 2 Ohm resistor (to account for the Ron of an electrical switch).

Note 3: L1, L2 and C1 should be located as close to pins as possible.



# J1 J2 J5

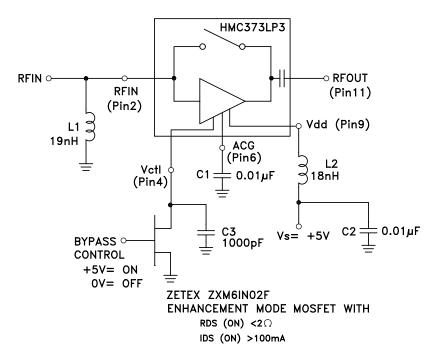
### List of Material

Item	Description	
J1 - J2	PC Mount SMA RF Connector	
J3 - J4	DC Pin	
J5	2 Pos DIP Switch	
C1	10000 pF Capacitor, 0402 Pkg.	
C2	10000 pF Capacitor, 0603 Pkg.	
СЗ	1000 pF Capacitor, 0402 Pkg.	
L1	19 nH Inductor, 0402 Pkg.	
L2	18 nH Inductor, 0603 Pkg.	
R1	2 Ohm Resistor, 0402 Pkg.	
U1	HMC373LP3 Amplifier	
PCB*	107177 Evaluation Board	
* Circuit Board Material: Rogers 4350		

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



# **Application Circuit**



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Note 1: Choose value of capacitor C1 for low frequency bypassing. A 0.01 μF ±10% capacitor is recommended.

Note 2: Pin 4 (Vctl) is the DC ground return for the circuit. The LNA is in the high gain mode when a short circuit is introduced to this pin through an external switch. The LNA is in bypass mode when an open circuit is introduced. For the data presented, switching is done through a two position DIP switch (J5) in series with a 2 Ohm resistor (to account for the Ron of an electrical switch).

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**AMPLIFIERS - SMT** 

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Notes: